SimElectronics[®]

User's Guide

R2012b

MATLAB® SIMULINK®



How to Contact MathWorks



(a)

www.mathworks.comWebcomp.soft-sys.matlabNewsgroupwww.mathworks.com/contact_TS.htmlTechnical Support

suggest@mathworks.com bugs@mathworks.com doc@mathworks.com service@mathworks.com info@mathworks.com Product enhancement suggestions Bug reports Documentation error reports Order status, license renewals, passcodes Sales, pricing, and general information



508-647-7000 (Phone) 508-647-7001 (Fax)

The MathWorks, Inc. 3 Apple Hill Drive Natick. MA 01760-2098

For contact information about worldwide offices, see the MathWorks Web site.

SimElectronics[®] User's Guide

© COPYRIGHT 2008–2012 by The MathWorks, Inc.

The software described in this document is furnished under a license agreement. The software may be used or copied only under the terms of the license agreement. No part of this manual may be photocopied or reproduced in any form without prior written consent from The MathWorks, Inc.

FEDERAL ACQUISITION: This provision applies to all acquisitions of the Program and Documentation by, for, or through the federal government of the United States. By accepting delivery of the Program or Documentation, the government hereby agrees that this software or documentation qualifies as commercial computer software or commercial computer software documentation as such terms are used or defined in FAR 12.212, DFARS Part 227.72, and DFARS 252.227-7014. Accordingly, the terms and conditions of this Agreement and only those rights specified in this Agreement, shall pertain to and govern the use, modification, reproduction, release, performance, display, and disclosure of the Program and Documentation by the federal government (or other entity acquiring for or through the federal government) and shall supersede any conflicting contractual terms or conditions. If this License fails to meet the government's needs or is inconsistent in any respect with federal procurement law, the government agrees to return the Program and Documentation, unused, to The MathWorks, Inc.

Trademarks

MATLAB and Simulink are registered trademarks of The MathWorks, Inc. See www.mathworks.com/trademarks for a list of additional trademarks. Other product or brand names may be trademarks or registered trademarks of their respective holders.

Patents

MathWorks products are protected by one or more U.S. patents. Please see www.mathworks.com/patents for more information.

Revision History

April 2008	Online only	New for Version 1.0 (Release 2008a+)
October 2008	Online only	Revised for Version 1.1 (Release 2008b)
March 2009	Online only	Revised for Version 1.2 (Release 2009a)
September 2009	Online only	Revised for Version 1.3 (Release 2009b)
March 2010	Online only	Revised for Version 1.4 (Release 2010a)
September 2010	Online only	Revised for Version 1.5 (Release 2010b)
April 2011	Online only	Revised for Version 1.6 (Release 2011a)
September 2011	Online only	Revised for Version 2.0 (Release 2011b)
March 2012	Online only	Revised for Version 2.1 (Release 2012a)
September 2012	Online only	Revised for Version 2.2 (Release 2012b)

Contents

Getting Started

Product Description Key Features
SimElectronics Assumptions and Limitations
Modeling Physical Networks with SimElectronics
Blocks
Required and Related Products
Product Requirements
Other Related Products
SimElectronics Block Libraries
Overview of SimElectronics Libraries
Opening SimElectronics Libraries
Modeling Electronic and Electromechanical
Systems
Essential Electronic Modeling Techniques
Overview of Modeling Rules
Required Blocks
Modeling Instantaneous Events
Using Simulink Blocks to Model Physical Components
Simulating an Electronic System
Selecting a Solver
Specifying Simulation Accuracy/Speed Tradeoff
Avoiding Simulation Issues
Running a Time-Domain Simulation
Running a Small-Signal Frequency-Domain Analysis

DC Motor Model	1-18
Overview of DC Motor Example	1-18
Selecting Blocks to Represent System Components	1-18
Building the Model	1-19
Specifying Model Parameters	1-21
Configuring the Solver Parameters	1-28
Running the Simulation and Analyzing the Results	1-29
Triangle Wave Generator Model	1-32
Overview of Triangle Wave Generator Example	1-32
Selecting Blocks to Represent System Components	1-32
Building the Model	1 - 34
Dunning the motion and the motion of the second sec	1-04
Specifying Model Parameters	1-36

Modeling an Electronic System

2 Parameterizing Blocks from Datasheets 2-2Parameterize a Piecewise Linear Diode Model 2-4Parameterize an Exponential Diode from a 2-7Datasheet Parameterize an Exponential Diode from SPICE Netlist 2-112 - 15Parameterize an Op-Amp from a Datasheet Additional Parameterization Workflows 2 - 17Validation Using Data from SPICE Tool 2 - 17Parameter Tuning Against External Data 2 - 17Building an Equivalent Model of a SPICE Netlist 2 - 17Selecting the Output Model for Logic Blocks 2 - 18

Available Output Models	2-18
Quadratic Model Output and Parameters	2-19
Simulating Thermal Effects in Semiconductors	2-22
Using the Thermal Ports	2-22
Thermal Model for Semiconductor Blocks	2-24
Thermal Mass Parameterization	2-25
Electrical Behavior Depending on Temperature	2-26
Improving Numerical Performance	2-26
Simulating Thermal Effects in Rotational and	
Translational Actuators	2-28
Using the Thermal Ports	2-28
Thermal Model for Actuator Blocks	2-30

A

Examples

Examples	 A-2

Index

Getting Started

- "Product Description" on page 1-2
- "SimElectronics Assumptions and Limitations" on page 1-3
- "Modeling Physical Networks with SimElectronics Blocks" on page 1-4
- "Required and Related Products" on page 1-5
- "SimElectronics Block Libraries" on page 1-6
- "Modeling Electronic and Electromechanical Systems" on page 1-10
- "Essential Electronic Modeling Techniques" on page 1-11
- "Simulating an Electronic System" on page 1-15
- "DC Motor Model" on page 1-18
- "Triangle Wave Generator Model" on page 1-32

Product Description

Model and simulate electronic and mechatronic systems

SimElectronics[®] provides component libraries for modeling and simulating electronic and mechatronic systems. It includes models of semiconductor, motor, drive, sensor, and actuator components. You can use these components to perform system-level design of electromechanical actuation systems and to evaluate analog circuit architectures using behavioral models.

Models created from SimElectronics components support control and algorithm design in electronic and mechatronic systems, such as vehicle body electronics, aircraft servomechanisms, and audio power amplifiers. For circuit modeling, the semiconductor models include nonlinear and dynamic temperature effects, enabling you to select components in amplifiers, analog-to-digital converters, phase-locked loops, and other circuits.

Key Features

- More than 90 electronic and electromechanical components with physical connections, including sensors, semiconductors, and actuators
- Parameterization options, enabling key parameter values to be entered directly from industry datasheets
- Semiconductor models with temperature-dependent behavior and configurable thermal ports
- Ideal and nonideal model variants, enabling adjustment of model fidelity
- Ability to extend component libraries using the SimscapeTM language
- Access to linearization and steady-state calculation capabilities in Simscape
- Support for C-code generation with Simulink[®] Coder[™]

SimElectronics Assumptions and Limitations

SimElectronics contains blocks that let you model electronic and mechatronic systems at a speed and level of fidelity that is appropriate for system-level analysis. The blocks let you perform tradeoff analyses to optimize system design, for example, by testing various algorithms with different circuit implementations. The library contains blocks that use either high-level or more detailed models to simulate components. SimElectronics does not have the capability to:

- Model large circuits with dozens of analog components, such as a complete transceiver.
- Perform either layout (physical design) tasks, or the associated implementation tasks such as layout versus schematic (LVS), design rule checking (DRC), parasitic extraction, and back annotation.
- Model 3-D parasitic effects that are typically important for high-frequency applications.

For these types of requirements, you must use an EDA package specifically designed for the implementation of analog circuits.

Another MathWorks[®] product, SimPowerSystems[™] software, is better suited for power system networks where:

- The underlying equations are predominantly linear (e.g., transmission lines and linear machine models).
- Three-phase motors and generators are used.

SimPowerSystems has blocks and solvers specifically designed for these types of applications.

1

Modeling Physical Networks with SimElectronics Blocks

SimElectronics is part of the Simulink Physical Modeling family. Models using SimElectronics are essentially Simscape block diagrams. To build a system-level model with electrical blocks, use a combination of SimElectronics blocks and other Simscape and Simulink blocks. You can connect SimElectronics blocks directly to Simscape blocks. You can connect Simulink blocks through the Simulink-PS Converter and PS-Simulink Converter blocks from the Simscape Utilities library. These blocks convert electrical signals to and from Simulink mathematical signals. For more information about connecting different types of blocks, see "Connector Ports and Connection Lines" and "Connecting Simscape Diagrams to Simulink Sources and Scopes" in the Simscape documentation.

For more information about basic principles to follow when building an electrical model with SimElectronics, see "Basic Principles of Modeling Physical Networks" in the Simscape documentation.

Required and Related Products

Product Requirements

SimElectronics software is an extension of Simscape product, expanding its capabilities to model and simulate electronic and electromechanical elements and devices.

SimElectronics software requires these products:

- MATLAB®
- Simulink
- Simscape

Other Related Products

The SimElectronics product page at the MathWorks Web site lists the toolboxes and blocksets that extend the capabilities of MATLAB and Simulink. These products can enhance your use of SimElectronics software in various applications.

For more information about MathWorks software products, see:

- The online documentation for that product if it is installed
- The MathWorks Web site at www.mathworks.com

SimElectronics Block Libraries

In this section...

"Overview of SimElectronics Libraries" on page 1-6

"Opening SimElectronics Libraries" on page 1-6

Overview of SimElectronics Libraries

SimElectronics libraries provide blocks for modeling electromechanical and electrical systems within the Simulink environment. You can also create custom components either by combining SimElectronics components as Simulink subsystems, or by using the Simscape language.

Note SimElectronics follows the standard Simulink conventions where block inputs and outputs are called *ports*. In SimElectronics, each port represents a single electrical terminal.

A SimElectronics model can contain blocks from the standard SimElectronics library, from the Simscape Foundation and Utilities libraries, or from a custom library you create, using the Simscape language, based on the Simscape Foundation electrical domain. A model can also include blocks from other Simscape add-on products, as well as Simulink blocks.

Opening SimElectronics Libraries

There are two ways to access SimElectronics blocks:

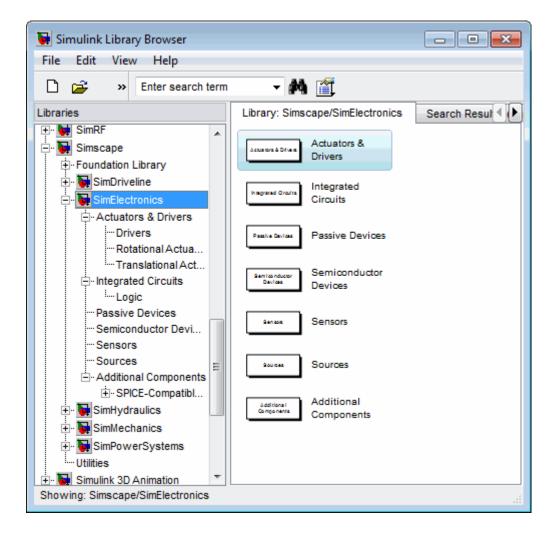
- "Using the Simulink Library Browser to Access the Block Libraries" on page 1-7
- "Using the Command Prompt to Access the Block Libraries" on page 1-8

Using the Simulink Library Browser to Access the Block Libraries

You can access the blocks through the Simulink Library Browser. To display the Library Browser, click the **Library Browser** button in the toolbar of the MATLAB desktop or Simulink model window:



Alternatively, you can type simulink in the MATLAB Command Window. Then expand the **Simscape** entry in the contents tree.



Using the Command Prompt to Access the Block Libraries

Another way to access the block libraries is to open them individually by using the command prompt:

• To open just the SimElectronics library, type elec_lib in the MATLAB Command Window.

- To open the Simscape library (to access the utility blocks, as well as electrical sources, sensors, and other Foundation library blocks), type simscape in the MATLAB Command Window.
- To open the main Simulink library (to access generic Simulink blocks), type simulink in the MATLAB Command Window.

The SimElectronics library window is shown in the following figure. Each icon in the window represents a library. Some of these libraries contain second-level sublibraries. Double-click an icon to open the corresponding library.

🙀 Library: elec_lib	
File Edit View Format Help	
Actuators & Drivers	ircuits Passive Devices Devices Devices
Sensors	Sources Additional Components

Modeling Electronic and Electromechanical Systems

When you model and analyze an electronic or electromechanical system using SimElectronics software, your workflow might include the following tasks:

1 Create a Simulink model that includes electronic or electromechanical components.

In the majority of applications, it is most natural to model the physical system using Simscape and SimElectronics blocks, and then develop the controller or signal processing algorithm in Simulink.

For more information about modeling the physical system, see "Essential Electronic Modeling Techniques" on page 1-11.

2 Define component data by specifying electrical or mechanical properties as defined on a datasheet.

For more information about parameterizing blocks, see "Parameterizing Blocks from Datasheets" on page 2-2.

3 Configure the solver options.

For more information about the settings that most affect the solution of a physical system, see "Setting Up Solvers for Physical Models" in the Simscape documentation..

4 Run the simulation.

For more information on how to perform time-domain simulation of an electronic system, see "Simulating an Electronic System" on page 1-15.

Essential Electronic Modeling Techniques

In this section ...

"Overview of Modeling Rules" on page 1-11

"Required Blocks" on page 1-13

"Modeling Instantaneous Events" on page 1-13

"Using Simulink Blocks to Model Physical Components" on page 1-13

Overview of Modeling Rules

SimElectronics models are essentially Simscape block diagrams. To build a system-level model with electrical blocks, use a combination of SimElectronics blocks and other Simscape and Simulink blocks. You can connect SimElectronics blocks directly to Simscape blocks. You can connect Simulink blocks through the Simulink-PS Converter and PS-Simulink Converter blocks from the Simscape Utilities library. These blocks convert electrical signals to and from Simulink mathematical signals.

The rules that you must follow when building an electronic or electromechanical model are described in "Basic Principles of Modeling Physical Networks" in the Simscape documentation. This section briefly reviews these rules.

- SimElectronics blocks, in general, feature Conserving ports and Physical Signal inports and outports ▷.
- There are two main types of Physical Conserving ports used in SimElectronics blocks: electrical and mechanical rotational. Each type has specific Through and Across variables associated with it.
- You can connect Conserving ports only to other Conserving ports of the same type.
- The Physical connection lines that connect Conserving ports together are nondirectional lines that carry physical variables (Across and Through variables, as described above) rather than signals. You cannot connect Physical lines to Simulink ports or to Physical Signal ports.

- Two directly connected Conserving ports must have the same values for all their Across variables (such as voltage or angular velocity).
- You can branch Physical connection lines. When you do so, components directly connected with one another continue to share the same Across variables. Any Through variable (such as current or torque) transferred along the Physical connection line is divided among the multiple components connected by the branches. How the Through variable is divided is determined by the system dynamics.

For each Through variable, the sum of all its values flowing into a branch point equals the sum of all its values flowing out.

- You can connect Physical Signal ports to other Physical Signal ports with regular connection lines, similar to Simulink signal connections. These connection lines carry physical signals between SimElectronics blocks.
- You can connect Physical Signal ports to Simulink ports through special converter blocks. Use the Simulink-PS Converter block to connect Simulink outports to Physical Signal inports. Use the PS-Simulink Converter block to connect Physical Signal outports to Simulink inports.
- Unlike Simulink signals, which are essentially unitless, Physical Signals can have units associated with them. SimElectronics block dialogs let you specify the units along with the parameter values, where appropriate. Use the converter blocks to associate units with an input signal and to specify the desired output signal units.

For examples of applying these rules when creating an actual electromechanical model, see "DC Motor Model" on page 1-18.

MathWorks recommends that you build, simulate, and test your model incrementally. Start with an idealized, simplified model of your system, simulate it, verify that it works the way you expected. Then incrementally make your model more realistic, factoring in effects such as motor shaft compliance, hard stops, and the other things that describe real-world phenomena. Simulate and test your model at every incremental step. Use subsystems to capture the model hierarchy, and simulate and test your subsystems separately before testing the whole model configuration. This approach helps you keep your models well organized and makes it easier to troubleshoot them.

Required Blocks

Each topologically distinct physical network in a diagram requires exactly one Solver Configuration block, found in the Simscape Utilities library. The Solver Configuration block specifies global environment information for simulation and provides parameters for the solver that your model needs before you can begin simulation. For more information, see the Solver Configuration block reference page.

Each electrical network requires an Electrical Reference block. This block establishes the electrical ground for the circuit. Networks with electromechanical blocks also require a Mechanical Rotational Reference block. For more information about using reference blocks, see "Grounding Rules" in the Simscape documentation.

Modeling Instantaneous Events

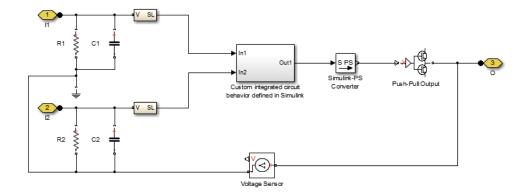
When working with SimElectronics software, your model may include Simulink blocks that create instantaneous changes to the physical system inputs through the Simulink-PS Converter block, such as those associated with events or discrete sampling. When you build this type of model, make sure the corresponding zero crossings are generated.

Many blocks in the Simulink library generate these zero crossings by default. For example, the Pulse Generator block produces a discrete-time output by default, and generates the corresponding zero crossings. To model instantaneous events, select Use local settings or Enable all for the **Zero crossing control** option under the model's Solver Configuration Parameters to generate zero crossings. For more information about zero crossing control, see "Zero-crossing control" in the Simulink documentation.

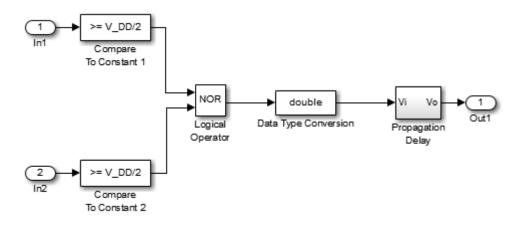
Using Simulink Blocks to Model Physical Components

To run a fast simulation that approximates the behavior of the physical components in a system, you may want to use Simulink blocks to model of one or more physical components.

The Modeling an Integrated Circuit example uses Simulink to model a physical component. The Behavioral Model part of the example includes a subsystem, comprised of Simulink blocks, that implements the custom integrated circuit behavior. 1



The subsystem is shown in the following illustration.



The Simulink Logical Operator block implements the behavioral model of the two-input NOR gate. Using Simulink in this manner introduces algebraic loops, unless you place a lag somewhere between the physical signal inputs and outputs. In this case, a first-order lag is included in the Propagation Delay subsystem to represent the delay due to gate capacitances. For applications where no lag is required, use blocks from the Physical Signals sublibrary in the Simscape Foundation Library to implement the desired functionality.

Simulating an Electronic System

In this section ...

"Selecting a Solver" on page 1-15

"Specifying Simulation Accuracy/Speed Tradeoff" on page 1-15

"Avoiding Simulation Issues" on page 1-16

"Running a Time-Domain Simulation" on page 1-17

"Running a Small-Signal Frequency-Domain Analysis" on page 1-17

Selecting a Solver

SimElectronics software supports all of the continuous-time solvers that Simscape supports. For more information, see "Setting Up Solvers for Physical Models" in the Simscape documentation.

You can select any of the supported solvers for running a SimElectronics simulation. The variable-step solvers, ode23t and ode15s, are recommended for most applications because they run faster and copy better for systems with a range of both fast and slow dynamics. The ode23t solver is closest to the solver that SPICE traditionally uses.

To use Simulink Coder software to generate standalone C or C++ code from your model, you must use the ode14x solver. For more information about code generation, see "Code Generation" in the Simscape documentation.

Specifying Simulation Accuracy/Speed Tradeoff

To trade off accuracy and simulation time, adjust one or more of the following parameters:

- **Relative tolerance** (in the Configuration Parameters dialog box)
- Absolute tolerance (in the Configuration Parameters dialog box)
- Max step size (in the Configuration Parameters dialog box)
- **Constraint Residual Tolerance** (in the Solver Configuration block dialog box)

In most cases, the default tolerance values produce accurate results without sacrificing unnecessary simulation time. The parameter value that is most likely to be inappropriate for your simulation is **Max step size**, because the default value, auto, depends on the simulation start and stop times rather than on the amount by which the signals are changing during the simulation. If you are concerned about the solver's missing significant behavior, change the parameter to prevent the solver from taking too large a step.

The Simulink documentation describes the following parameters in more detail and provides tips on how to adjust them:

- "Relative tolerance"
- "Absolute tolerance"
- "Max step size"

The Solver Configuration block reference page in the Simscape documentation explains when to adjust the **Constraint Residual Tolerance** parameter value.

Avoiding Simulation Issues

If you experience a simulation issue, first read "Troubleshooting Simulation Errors" in the Simscape documentation to learn about general troubleshooting techniques.

Note SimElectronics software does not have the ability to model large circuits with dozens of analog components. If you encounter convergence issues when trying to simulate a model with more than a few tens of transistors, you may find that the limitations of SimElectronics software prevent you from achieving convergence with any set of simulation parameter values.

There are a few techniques you can apply to any SimElectronics model to overcome simulation issues:

• Add parasitic capacitors and/or resistors (specifically, junction capacitance and ohmic resistance) to the circuit to avoid numerical issues. The Astable Oscillator example uses these devices.

• Adjust the current and voltage sources so they start at zero and ramp up to their final values rather than starting at nonzero values.

"Modeling Instantaneous Events" on page 1-13 and "Using Simulink Blocks to Model Physical Components" on page 1-13 describe how to avoid simulation errors in the presence of specific SimElectronics model configurations.

Running a Time-Domain Simulation

When you run a time-domain simulation, SimElectronics software uses the Simscape solver to analyze the physical system in the Simulink environment. For more information, see "How Simscape Simulation Works" in the Simscape documentation.

Running a Small-Signal Frequency-Domain Analysis

You can perform small-signal analysis for Simscape and SimElectronics models using linearization capabilities of Simulink software. For more information, see "Linearize an Electronic Circuit" in the Simscape documentation.

DC Motor Model

In this section...

"Overview of DC Motor Example" on page 1-18

"Selecting Blocks to Represent System Components" on page 1-18

"Building the Model" on page 1-19

"Specifying Model Parameters" on page 1-21

"Configuring the Solver Parameters" on page 1-28

"Running the Simulation and Analyzing the Results" on page 1-29

Overview of DC Motor Example

In this example, you model a DC motor driven by a constant input signal that approximates a pulse-width modulated signal and look at the current and rotational motion at the motor output.

To see the completed model, open the Controlled DC Motor example.

Selecting Blocks to Represent System Components

Select the blocks to represent the input signal, the DC motor, and the motor output displays.

The following table describes the role of the blocks that represent the system components.

Block	Description
Solver Configuration	Defines solver settings that apply to all physical modeling blocks.
DC Voltage Source	Generates a DC signal.
Controlled PWM Voltage	Generates the signal that approximates a pulse-width modulated motor input signal.
H-Bridge	Drives the DC motor.

Block	Description	
Current Sensor	Converts the electrical current that drives the motor into a physical signal proportional to the current.	
Ideal Rotational Motion Sensor	Converts the rotational motion of the motor into a physical signal proportional to the motion.	
DC Motor	Converts input electrical signal into mechanical motion.	
PS-Simulink Converter	Converts the input physical signal to a Simulink signal.	
Scope	Displays motor current and rotational motion.	
Electrical Reference	Provides the electrical ground.	
Mechanical Rotational Reference	Provides the mechanical ground.	

Building the Model

Create a Simulink model, add blocks to the model, and connect the blocks.

- 1 Create a new model.
- **2** Add to the model the blocks listed in the following table. The Library column of the table specifies the hierarchical path to each block.

Block	Library Path	Quantity
Solver Configuration	Simscape > Utilities	1
DC Voltage Source	Simscape > Foundation Library > Electrical > Electrical Sources	1
Controlled PWM Voltage	Simscape > SimElectronics > Actuators & Drivers > Drivers	1

1

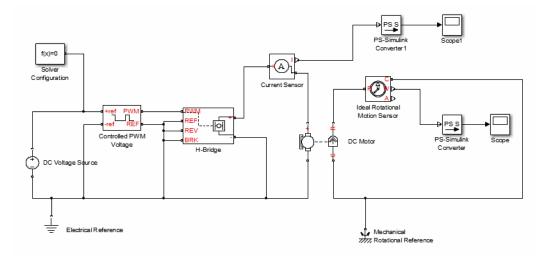
Block	Library Path	Quantity
H-Bridge	Simscape > SimElectronics > Actuators & Drivers > Drivers	1
Current Sensor	Simscape > Foundation Library > Electrical > Electrical Sensors	1
Ideal Rotational Motion Sensor	Simscape > Foundation Library > Mechanical > Mechanical Sensors	1
DC Motor	Simscape > SimElectronics > Actuators & Drivers > Rotational Actuators	1
PS-Simulink Converter	Simscape > Utilities	2
Scope	Simulink > Commonly Used Blocks	2
Electrical Reference	Simscape > Foundation Library > Electrical > Electrical Elements	1
Mechanical Rotational Reference	Simscape > Foundation Library > Mechanical > Rotational Elements	1

Note You can use the Simscape function **ssc_new** with a domain type of **electrical** to create a Simscape model that contains the following blocks:

- Simulink-PS Converter
- PS-Simulink Converter
- Scope
- Solver Configuration

• Electrical Reference

This function also selects the Simulink ode15s solver.



3 Connect the blocks as shown in the following figure.

Now you are ready to specify block parameters.

Specifying Model Parameters

Specify the following parameters to represent the behavior of the system components:

- "Model Setup Parameters" on page 1-21
- "Motor Input Signal Parameters" on page 1-22
- "Motor Parameters" on page 1-25
- "Current Display Parameters" on page 1-26
- "Torque Display Parameters" on page 1-27

Model Setup Parameters

The following blocks specify model information that is not specific to a particular block:

• Solver Configuration

- Electrical Reference
- Mechanical Rotational Reference

As with Simscape models, you must include a Solver Configuration block in each topologically distinct physical network. This example has a single physical network, so use one Solver Configuration block with the default parameter values.

You must include an Electrical Reference block in each SimElectronics network. You must include a Mechanical Rotational Reference block in each network that includes electromechanical blocks. These blocks do not have any parameters.

For more information about using reference blocks, see "Grounding Rules" in the Simscape documentation.

Motor Input Signal Parameters

You generate the motor input signal using three blocks:

- The DC Voltage Source block generates a constant signal.
- The Controlled PWM Voltage block generates a pulse-width modulated signal.
- The H-Bridge block drives the motor.

In this example, all input ports of the H-Bridge block except the PWM port are connected to ground. As a result, the H-Bridge block behaves as follows:

- When the motor is on, the H-Bridge block connects the motor terminals to the power supply.
- When the motor is off, the H-Bridge block acts as a freewheeling diode to maintain the motor current.

In this example, you simulate the motor with a constant current whose value is the average value of the PWM signal. By using this type of signal, you set up a fast simulation that estimates the motor behavior.

1 Set the DC Voltage Source block parameters as follows:

• Constant voltage = 2.5

🙀 Block Parameters: DC Volta	ge Source		
DC Voltage Source			
The ideal voltage source maintains a constant voltage across its output terminals, independent of the current flowing through the source. The output voltage is defined by the Constant voltage parameter, and can be any real value. View source for DC Voltage Source			
Parameters			
Constant voltage:	2.5	v •	
		OK Cancel Help Apply	

- **2** Set the Controlled PWM Voltage block parameters as follows:
 - PWM frequency = 4000

1

• Simulation mode = Averaged

This value tells the block to generate an output signal whose value is the average value of the PWM signal. Simulating the motor with an averaged signal estimates the motor behavior in the presence of a PWM signal. To validate this approximation, use value of PWM for this parameter.

📓 Block Parameters: Controlled PWM Voltage 🗾 📧			
Controlled PWM Voltage			
This block represents a Pulse-Width Modulated (PWM) voltage source across its PWM and REF ports that depends on the reference voltage Vref across its +ref and -ref ports. The duty cycle in percent is given by 100*(Vref-Vmin)/(Vmax-Vmin) where Vmin and Vmax are the minimum and maximum values for Vref. The output voltage amplitude is set by the Output voltage amplitude.			
At time zero, the pulse is initialize	d as high (unless the duty cycle is set to zero).		
The Simulation mode can be set to PWM or Averaged. In PWM mode, the output is a PWM signal. In Averaged mode, the output is constant with value equal to the averaged PWM signal.			
Parameters			
PWM frequency:	4000	Hz 👻	
Input value Vmin for 0% duty cycle:	0	V •	
Input value Vmax for 100% duty cycle:	5	V •	
Output voltage amplitude:	5	۷ 🗸	
Simulation mode:	Averaged	•	
	OK Cancel	Help Apply	

3 Set the H-Bridge block parameters as follows:

• Simulation mode = Averaged

This value tells the block to generate an output signal whose value is the average value of the PWM signal. Simulating the motor with an averaged signal estimates the motor behavior in the presence of a PWM signal. To validate this approximation, use value of PWM for this parameter.

Block Parameters: H-Bridge
H-Bridge
This block represents an H-bridge motor driver.
The block can be driven by the Controlled PWM Voltage block in PWM or Averaged mode. In PWM mode, the motor is powered if the PWM port voltage V is above the Enable threshold voltage. In Averaged mode, the PWM port voltage divided by the PWM signal amplitude parameter defines the ratio of the on-time to the PWM period. Using this ratio and assumptions about the load, the block applies an average voltage to the load that achieves the correct average load current. The Simulation mode parameter value must be the same for the Controlled PWM Voltage and H-Bridge blocks. If the REV port voltage is greater than the Reverse threshold voltage, then the output voltage polarity is reversed. If the BRK port voltage is greater than the Braking threshold voltage, then the output terminals are short circuited via one bridge arm in series with the parallel combination of a second bridge arm and a freewheeling diode.
Voltages at ports PWM, REV and BRK are defined relative to the REF port.
Parameters
Simulation Mode & Load Assumptions Input Thresholds Bridge Parameters
Simulation mode: Averaged Load current characteristics: Smoothed
OK Cancel Help Apply

Motor Parameters

Configure the block that models the motor.

Set the Motor block parameters as follows, leaving the unit settings at their default values where applicable:

- Electrical Torque tab:
 - Model parameterization = By rated power, rated speed & no-load speed

- Armature inductance = 0.01
- No-load speed = 4000
- Rated speed (at rated load) = 2500
- Rated load (mechanical power) = 10
- Rated DC supply voltage = 12
- Mechanical tab:
 - Rotor inertia = 2000
 - Rotor damping = 1e-06

Current Display Parameters

Specify the parameters of the blocks that create the motor current display:

- Current Sensor block
- PS-Simulink Converter1 block
- Scope1 block

Of the three blocks, only the PS-Simulink Converter1 block has parameters. Set the PS-Simulink Converter1 block **Output signal unit** parameter to A to indicate that the block input signal has units of amperes.

Block Parameters: PS-Simulink1
PS-Simulink Converter
Converts the input Physical Signal to a unitless Simulink output signal.
The unit expression in 'Output signal unit' parameter must match or be commensurate with the unit of the Physical Signal and determines the conversion from the Physical Signal to the unitless Simulink output signal.
'Apply affine conversion' check box is only relevant for units with offset (such as temperature units).
Parameters
Output signal unit: A
Apply affine conversion
OK Cancel Help Apply

Torque Display Parameters

Specify the parameters of the blocks that create the motor torque display:

- Ideal Rotational Motion Sensor block
- PS-Simulink Converter block
- Scope block

Of the three blocks, only the PS-Simulink Converter block has parameters you need to configure for this example. Set the PS-Simulink Converter block **Output signal unit** parameter to rpm to indicate that the block input signal has units of revolutions per minute.

Note You must type this parameter value. It is not available in the drop-down list.

1

🙀 Block Parameters: PS-Simulink
PS-Simulink Converter
Converts the input Physical Signal to a unitless Simulink output signal.
The unit expression in 'Output signal unit' parameter must match or be commensurate with the unit of the Physical Signal and determines the conversion from the Physical Signal to the unitless Simulink output signal.
'Apply affine conversion' check box is only relevant for units with offset (such as temperature units).
Parameters
Output signal unit: rpm 👻
Apply affine conversion
OK Cancel Help Apply

Configuring the Solver Parameters

Configure the solver parameters to use a continuous-time solver because SimElectronics models only run with a continuous-time solver. Increase the maximum step size the solver can take so the simulation runs faster.

- In the model window, select Simulation > Model Configuration Parameters to open the Configuration Parameters dialog box.
- 2 Select ode15s (Stiff/NDF) from the Solver list.
- 3 Enter 1 for the Max step size parameter value.
- 4 Click OK.

🍓 Configuration Parameters: unt	itled/Configuration (Active)		×
Select:	Simulation time			<u>^</u>
Solver	Start time: 0.0		Stop time: 10	
	Start time: 0.0 Solver options Type: Max step size: Min step size: Initial step size: Solver reset method: Number of consecutive Solver Jacobian method Tasking and sample tin Tasking mode for perior	e min steps: bd: me options bdic sample times: le rate transition for data transfe e indicates higher task priority Use local settings 10*128*eps	Solver: Relative tolerance: Absolute tolerance: Shape preservation: Maximum order: 1 auto Auto r	E
<		III	ОК	► Apply

For more information about configuring solver parameters, see "Simulating an Electronic System" on page 1-15.

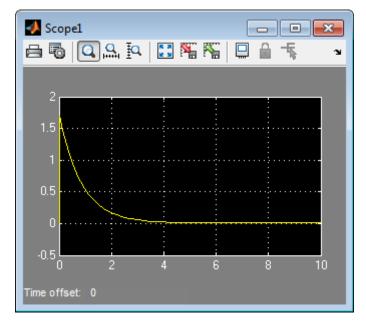
Running the Simulation and Analyzing the Results

In this part of the example, you run the simulation and plot the results.

In the model window, select **Simulation > Run** to run the simulation.

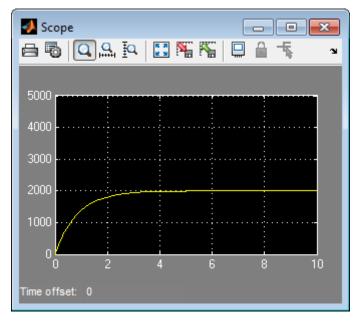
To view the motor current and torque in the Scope windows, double-click the Scope blocks. You can do this before or after you run the simulation.

Note By default, the scope displays appear stacked on top of each other on the screen, so you can only see one of them. Click and drag the windows to reposition them.



The following plot shows the motor current.

Motor Current



The next plot shows the motor rpm.

Motor RPM

As expected, the motor runs at about 2000 rpm when the applied DC voltage is 2.5 V.

Triangle Wave Generator Model

In this section ...

"Overview of Triangle Wave Generator Example" on page 1-32

"Selecting Blocks to Represent System Components" on page 1-32

"Building the Model" on page 1-34

"Specifying Model Parameters" on page 1-36

"Configuring the Solver Parameters" on page 1-44

"Running the Simulation and Analyzing the Results" on page 1-45

Overview of Triangle Wave Generator Example

In this example, you model a triangle wave generator using SimElectronics electrical blocks and custom SimElectronics electrical blocks, and then look at the voltage at the wave generator output.

You use a classic circuit configuration consisting of an integrator and a noninverting amplifier to generate the triangle wave, and use datasheets to specify block parameters. For more information, see "Parameterizing Blocks from Datasheets" on page 2-2.

To see the completed model, open the Triangle Wave Generator example.

Selecting Blocks to Represent System Components

First, you select the blocks to represent the input signal, the triangle wave generator, and the output signal display.

You model the triangle wave generator with a set of physical blocks bracketed by a Simulink-PS Converter block and a PS-Simulink Converter block. The wave generator consists of:

- Two operational amplifier blocks
- Resistors and a capacitor that work with the operational amplifiers to create the integrator and noninverting amplifier

• Simulink-PS Converter and PS-Simulink Converter blocks. The function of the Simulink-PS Converter and PS-Simulink Converter blocks is to bridge the physical part of the model, which uses physical signals, and the rest of the model, which uses unitless Simulink signals.

You have a manufacturer datasheet for the two operational amplifiers you want to model. Later in the example, you use the datasheet to parameterize the SimElectronics Band-Limited Op-Amp block.

Block	Description
Sine Wave	Generates a sinusoidal signal that controls the resistance of the Variable Resistor block.
Simulink-PS Converter	Converts the sinusoidal Simulink signal to a physical signal.
Solver Configuration	Defines solver settings that apply to all physical modeling blocks.
Electrical Reference	Provides the electrical ground.
Capacitor	Works with an operational amplifier and resistor block to create the integrator.
Resistor	Works with the operational amplifier and capacitor blocks to create the integrator and noninverting amplifier.
Variable Resistor	Supplies a time-varying resistance that adjusts the gain of the integrator, which in turn varies the frequency and amplitude of the generated triangular wave.
DC Voltage Source	Generates a DC reference signal for the operational amplifier block of the noninverting amplifier.
Voltage Sensor	Converts the electrical voltage at the output of the integrator into a physical signal proportional to the current.

The following table describes the role of the blocks that represent the system components.

1

Block	Description
PS-Simulink Converter	Converts the output physical signal to a Simulink signal.
Scope	Displays the triangular output wave.
Band-Limited Op-Amp	Works with the capacitor and resistor to create an integrator and a noninverting amplifier.
Diode	Limit the output of the Band-Limited Op-Amp block, to make the output waveform independent of supply voltage.

Building the Model

Create a Simulink model, add blocks to the model, and connect the blocks.

- 1 Create a new model.
- **2** Add to the model the blocks listed in the following table. The Library Path column of the table specifies the hierarchical path to each block.

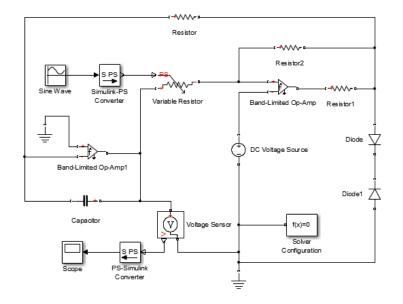
Block	Library Path	Quantity
Sine Wave	Simulink > Sources	1
Simulink-PS Converter	Simscape > Utilities	1
Solver Configuration	Simscape > Utilities	1
Electrical Reference	Simscape > Foundation Library > Electrical > Electrical Elements	1
Capacitor	Simscape > Foundation Library > Electrical > Electrical Elements	1
Resistor	Simscape > Foundation Library > Electrical > Electrical Elements	3

Block	Library Path	Quantity
Variable Resistor	Simscape > Foundation Library > Electrical > Electrical Elements	1
DC Voltage Source	Simscape > Foundation Library > Electrical > Electrical Sources	1
Voltage Sensor	Simscape > Foundation Library > Electrical > Electrical Sensors	1
PS-Simulink Converter	Simscape > Utilities	1
Scope	Simulink > Commonly Used Blocks	1
Band-Limited Op-Amp	Simscape > SimElectronics > Integrated Circuits	2
Diode	Simscape > SimElectronics > Semiconductor Devices	2

Note You can use the Simscape function ssc_new with a domain type of electrical to create a Simscape model that contains the following blocks:

- Simulink-PS Converter
- PS-Simulink Converter
- Scope
- Solver Configuration
- Electrical Reference

This function also selects the Simulink ode15s solver.



3 Connect the blocks as shown in the following figure.

Now you are ready to specify block parameters.

Specifying Model Parameters

Specify the following parameters to represent the behavior of the system components:

- "Model Setup Parameters" on page 1-36
- "Input Signal Parameters" on page 1-37
- "Triangle Wave Generator Parameters" on page 1-39
- "Signal Display Parameters" on page 1-44

Model Setup Parameters

The following blocks specify model information that is not specific to a particular block:

- Solver Configuration
- Electrical Reference

As with Simscape models, you must include a Solver Configuration block in each topologically distinct physical network. This example has a single physical network, so use one Solver Configuration block with the default parameter values.

You must include an Electrical Reference block in each SimElectronics network. This block does not have any parameters.

Input Signal Parameters

Generate the sinusoidal control signal using the Sine Wave block.

Set the Sine Wave block parameters as follows:

- Amplitude = 0.5e4
- Bias = 1e4
- Frequency = pi/5e-4

Source Block Parameters: Sine Wave				
Sine Wave				
Output a sine wave:				
O(t) = Amp*Sin(Freq*t+Phase) + Bias				
Sine type determines the computational technique used. The parameters in the two types are related through:				
Samples per period = 2*pi / (Frequency * Sample time)				
Number of offset samples = Phase * Samples per period / (2*pi)				
Use the sample-based sine type if numerical problems due to running for large times (e.g. overflow in absolute time) occur.				
Parameters				
Sine type: Time based				
Time (t): Use simulation time				
Amplitude:				
0.5e4				
Bias:				
1e4				
Frequency:				
pi/5e-4				
Phase (rad):				
0				
Sample time:				
0				
☑ Interpret vector parameters as 1-D				
OK Cancel Help Apply				

Triangle Wave Generator Parameters

Configure the blocks that model the physical system that generates the triangle wave:

- Integrator Band-Limited Op-Amp, Capacitor, and Resistor blocks
- Noninverting amplifier Band-Limited Op-Amp1, Resistor2, and Variable Resistor blocks
- Resistor1
- Diode and Diode1
- Simulink-PS Converter and PS-Simulink Converter blocks that bridge the physical part of the model and the Simulink part of the model.
- **1** Accept the default parameters for the Simulink-PS Converter block. These parameters establish the units of the physical signal at the block output such that they match the expected default units of the Variable Resistor block input.
- **2** Set the two Band-Limited Op-Amp block parameters for the LM7301 device with a +-20V power supply:
 - The datatsheet gives the gain as 97dB, which is equivalent to $10^{(97/20)}=7.080e4$. Set the **Gain**, A parameter to 7e4.
 - The datatsheet gives input resistance as 39Mohms. Set Input resistance, Rin to 39e6.
 - Set **Output resistance**, **Rout** to 0 ohms. The datatsheet does not quote a value for Rout, but the term is insignificant compared to the output resistor that it drives.
 - Set minimum and maximum output voltages to -20 and +20 volts, respectively.
 - The datatsheet gives the maximum slew rate as 1.25V/µs. Set the Maximum slew rate, Vdot parameter to 1.25e6 V/s.

Block Parameters: Band-Limited Op-Amp				
Band-Limited Op-Amp				
This block models a band-limited op-amp. If the voltages at the positive and negative pins are denoted Vp and Vm, then the output voltage is given by $ \label{eq:voltage}$				
$Vout = A^{*}(Vp-Vm)^{1}/(s/(2^{*}pi^{*}f)+1)-Iout^{*}Rout$				
where A is the gain, Rout is the output resistance, Iout is the output current, s is the Laplace operator, and f is the 3dB bandwidth. The input current is given by (Vp-Vm)/Rin where Rin is the input resistance. The no-load output voltage is limited the range Vmin to Vmax, and the slew rate is limited to +-Vdot.				
The Initial output voltage, V0, sets the initial op-amp output voltage. Note that this does not take account of any voltage drop across Rout. The initial condition is not used if you select the Start simulation from steady state option in the Solver Configuration block.				
Parameters				
Gain, A:	7e4			
Input resistance, Rin:	39e6	Ohm 👻		
Output resistance, Rout:	0	Ohm 👻		
Minimum output, Vmin:	-20	V •		
Maximum output, Vmax:	20	V •		
Maximum slew rate, Vdot:	1.25/1e-6	V/s 👻		
Bandwidth, f:	4еб	Hz 🔹		
Initial output voltage, V0:	0	V •		
	OK Cancel	Help Apply		

- **3** Set the two Diode block parameters for a 4.3V zener diode. To model a BZX384-B4V3, set block parameters as follows:
 - On the Main tab, set **Diode model** to Piecewise Linear Zener. This selects a simplified zener diode model that is more than adequate to test the correct operation of this circuit.
 - Leave the **Forward voltage** as 0.6V this is a typical value for most diodes.
 - The datatsheet gives the forward current as 250mA when the forward voltage is 1V. So that the Diode block matches this, set the **On** resistance to (1V 0.6V)/250mA = 1.6 ohms.
 - The datatsheet gives the reverse leakage current as $3\mu A$ at a reverse voltage of 1V. Therefore, set the **Off conductance** to $3\mu A/1V = 3e-6$ S.
 - The datatsheet gives the reverse voltage as 4.3V. On the Reverse Breakdown tab, set the **Reverse breakdown voltage Vz** to 4.3 V.

• Set the Zener resistance Rz to a suitably small number. The datatsheet quotes the zener voltage for a reverse current of 5mA. For the Diode block to be representative of the real device, the simulated reverse voltage should be close to 4.3V at 5mA. As Rz tends to zero, the reverse breakdown voltage will tend to Vz regardless of current, as the voltage-current gradient becomes infinite. However, for good numerical properties, Rz must not be made too small. If, say, you allow a 0.01V error on the zener voltage at 5mA, then Rz will be 0.01V/5mA = 2 ohms. Set the Zener resistance Rz parameter to this value.

his block represents a diode. Use the Diode model parameter to select one of the following model types:				
1] Piecewise Linear Diode. This option invokes the diode model from the Simscape Foundation Library.				
2] Piecewise Linear Zener Diode (i.e. piecewise linear diode with reverse breakdown characteristics). This modes identical to the Piecewise Linear Diode for reverse voltages above the Reverse Breakdown Voltage Vz. For oltages below Vz the diode breaks down with a low corresponding Zener Resistance Rz. 3] Exponential Diode. Uses the standard exponential diode equation $I = Is^*(exp(V/(N^*Vt))^{-1})$ where Is is the laturation current, Vt is the thermal voltage, and N is the emission coefficient (>=1). Vt is given by Vt = k*T/e where k is Boltzman's constant, T is the absolute Temperature of the p-n junction, and e is the magnitude of harde on an electron.				
aramet	ers			
		akdown Ohmic Resistance Capacitance Temperature Dependence		
Main	Reverse Breakdown	Ohmic Resistance	Capacitance	Temperature Dependence
	Reverse Breakdown	Piecewise Linear		Temperature Dependence
Diode				Temperature Dependence
Diode Forwa	model:	Piecewise Linear		· · · · ·
Diode Forwa On res	model: rd voltage:	Piecewise Linear		v

🚹 Block Parameters: Diode				×	
Diode	Diode				
This block represents a diode. Use the Diode model parameter to select one of the following model types:					
[1] Piecewise Linear Diode. This option invokes the diode model from the Simscape Foundation Library.					
[2] Piecewise Linear Zener Diode (i.e. piecewise linear diode with reverse breakdown characteristics). This model is identical to the Piecewise Linear Diode for reverse voltages above the Reverse Breakdown Voltage Vz. For voltages below Vz the diode breaks down with a low corresponding Zener Resistance Rz. [3] Exponential Diode. Uses the standard exponential diode equation $I = Is^*(exp(V/(N^*Vt))-1)$ where Is is the Saturation current, Vt is the thermal voltage, and N is the emission coefficient (>=1). Vt is given by Vt = k*T/e where k is Boltzmann's constant, T is the absolute Temperature of the p-n junction, and e is the magnitude of charge on a electron.					
Parameters					
Main Reverse Breakdown	Main Reverse Breakdown Ohmic Resistance Capacitance Temperature Dependence				
Zener resistance, Rz:	Zener resistance, Rz: 2 Ohm -				
Reverse breakdown voltage, Vz	Reverse breakdown voltage, Vz: 4.3 V 🗸			v 👻	
OK Cancel Help Apply					

- 4 The Voltage Sensor block does not have any parameters.
- **5** Accept the default parameters for the Variable Resistor block. These parameters establish the units of the physical signal at the block output such that they match the expected default units of the Variable Resistor block input.
- **6** Set the Capacitor block parameters as follows:
 - Capacitance = 2.5e-9
 - Initial voltage = 0.08

This value starts the oscillation in the feedback loop.

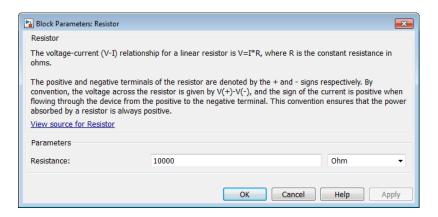
• Series resistance = 0

Block Parameters: Capacitor				
Capacitor				
Models a linear capacitor. The relationship between voltage V and and current I is $I=C^*dV/dt$ where C is the capacitance in farads.				
The Initial voltage parameter sets the initial voltage across the capacitor. Note that this value is not used if the solver configuration is set to Start simulation from steady state.				
The Series resistance and Parallel conductance represent small parasitic effects. The parallel conductance can be used to model dielectric losses and the series resistance used to represent the effective series resistance (ESR) of the capacitor. Simulation of some circuits may require the presence of the small series resistance. Consult the documentation for further details.				
View source for Capacitor				
Parameters				
Capacitance:	2.5e-9	F 🔹		
Initial voltage:	0.08	V •		
Series resistance:	0	Ohm 👻		
Parallel conductance: 0 1/Ohm -				
OK Cancel Help Apply				

- **7** Set the DC Voltage Source block parameters as follows:
 - Constant voltage = 0

📔 Block Parameters: DC Voltage Sourc	e		X	
DC Voltage Source				
The ideal voltage source maintains a constant voltage across its output terminals, independent of the current flowing through the source. The output voltage is defined by the Constant voltage parameter, and can be any real value.				
View source for DC Voltage Source				
Parameters				
Constant voltage:	0		V •	
		OK Cancel	Help Apply	

- 8 Set the Resistor block parameters as follows:
 - **Resistance** = 10000



- **9** Set the Resistor1 block parameters as follows:
 - Resistance = 1000

10 Set the Resistor2 block parameters as follows:

- **Resistance** = 10000
- **11** Accept the default parameters for the PS-Simulink Converter block. These parameters establish the units of the physical signal at the block output such that they match the expected default units of the Scope block input.

Signal Display Parameters

Specify the parameters of the Scope block to display the triangular output signal.

Double-click the Scope block and then double-click the Parameters button

to open the Scope parameters dialog box. On the **History** tab, clear the **Limit data points to last** check box.

Configuring the Solver Parameters

Configure the solver parameters to use a continuous-time solver because SimElectronics models only run with a continuous-time solver. You also change the simulation end time, tighten the relative tolerance for a more accurate simulation, and remove the limit on the number of simulation data points Simulink saves.

- In the model window, select Simulation > Model Configuration Parameters to open the Configuration Parameters dialog box.
- 2 In the Solver category in the Select tree on the left side of the dialog box:
 - Enter 2000e-6 for the **Stop time** parameter value.
 - Select ode23t (Mod. stiff/Trapezoidal) from the Solver list.
 - Enter 4e-5 for the **Max step size** parameter value.
 - Enter 1e-6 for the **Relative tolerance** parameter value.
- 3 In the Data Import/Export category in the Select tree:
 - Clear the Limit data points to last check box.
- 4 Click OK.

For more information about configuring solver parameters, see "Simulating an Electronic System" on page 1-15.

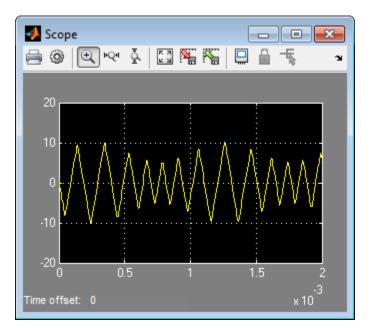
Running the Simulation and Analyzing the Results

Run the simulation and plot the results.

In the model window, select **Simulation > Run** to run the simulation.

To view the triangle wave in the Scope window, double-click the Scope block. You can do this before or after you run the simulation. 1

The following plot shows the voltage waveform. As the resistance of the Variable Resistor block increases, the amplitude of the output waveform increases and the frequency decreases.



Triangle Waveform Voltage

2

Modeling an Electronic System

- "Parameterizing Blocks from Datasheets" on page 2-2
- "Parameterize a Piecewise Linear Diode Model" on page 2-4
- "Parameterize an Exponential Diode from a Datasheet" on page 2-7
- "Parameterize an Exponential Diode from SPICE Netlist" on page 2-11
- "Parameterize an Op-Amp from a Datasheet" on page 2-15
- "Additional Parameterization Workflows" on page 2-17
- "Selecting the Output Model for Logic Blocks" on page 2-18
- "Simulating Thermal Effects in Semiconductors" on page 2-22
- "Simulating Thermal Effects in Rotational and Translational Actuators" on page 2-28

Parameterizing Blocks from Datasheets

SimElectronics software is a system-level simulation tool, which provides blocks with a commensurate level of fidelity. Block parameters are designed, where possible, to match the data found on manufacturer datasheets. For example, the bipolar transistor blocks support parameterization in terms of the small-signal quantities usually quoted on a datasheet, and the underlying model is simpler than that typically used by specialist EDA simulation tools. The smaller number of parameters and simpler underlying models can support MATLAB system performance analysis better, and thereby support design choices. Following system design, you can perform validation in hardware or more detailed modeling and validation using an EDA simulation tool.

The following parameterization examples illustrate various block parameterization techniques:

- Example 1: "Parameterize a Piecewise Linear Diode Model" on page 2-4
- Example 2: "Parameterize an Exponential Diode from a Datasheet" on page 2-7
- Example 3: "Parameterize an Exponential Diode from SPICE Netlist" on page 2-11
- Example 4: "Parameterize an Op-Amp from a Datasheet" on page 2-15

Most of the time, datasheets should be a sufficient source of parameters for SimElectronics blocks (see Examples 1, 2, and 4). Sometimes, there is need for more information than is available on the datasheet, and data can be augmented from a manufacturer SPICE netlist. For example, circuit performance may depend on one or two critical components, and increased accuracy is needed either for parameter values or the underlying model. SimElectronics libraries contain a SPICE-compatible sublibrary to support this case, and this is illustrated by Example 3. If you have many components that need to be modeled to a high level of accuracy, then Simulink cosimulation with a specialist circuit simulator may be a better option.

In mechatronic applications in particular, you may need to model input-output behavior of integrated circuits, such as PWM waveform generators and H-bridges. For these two examples, SimElectronics libraries contain abstracted-behavior equivalent blocks that you can use. Where you need to model other devices, possible options include creating your own abstracted model using the Simscape language, or using Simulink blocks. For an example of using Simulink blocks, see the Modeling an Integrated Circuit example.

When looking for a datasheet, make sure you have the originating manufacturer datasheet because some resellers abbreviate them.

For additional ways to parameterize and validate your model, see "Additional Parameterization Workflows" on page 2-17.

Parameterize a Piecewise Linear Diode Model

The Triangle Wave Generator example model, also described in "Triangle Wave Generator Model" on page 1-32, contains two zener diodes that regulate the maximum output voltage from an op-amp amplifier circuit. Each of these diodes is implemented with the SimElectronics Diode block, parameterized using the Piecewise Linear Zener option. This simple model is sufficient to check correct operation of the circuit, and requires fewer parameters than the Exponential option of the Diode block. However, when specifying the parameters, you need to take into account the bias condition that will be used in the circuit. This example explains how to do this.

Working voltage, $V_Z(V)$ at $I_{Ztest} = 5$ mA	4.3
Diode capacitance, C _d (pF)	450
Reverse current, $I_{\rm R}(\mu A)$ at $V_{\rm R}$ = 1 V	3
Forward voltage, $V_F(V)$ at $I_F = 5 \text{ mA}$	0.7

The Phillips Semiconductors datasheet for a BZX384–B4V3 gives the following data:

In the datasheet, the tabulated values for $\rm V_F$ are for higher forward currents. This value of 0.7V at 5mA is extracted from the datasheet current-voltage curve, and is chosen as it matches the zener current used when quoting the working voltage of 4.3V.

To match the datasheet values, the example sets the piecewise linear zener diode block parameters as follows:

- Forward voltage. Leave as default value of 0.6V. This is a typical value for most diodes, and the exact value is not critical. However, it is important that the value set is taken into account when calculating the **On resistance** parameter.
- On resistance. This is set using the datasheet information that the forward voltage is 0.7V when the current is 5mA. The voltage to be dropped by the On resistance parameter is 0.7V minus the Forward voltage parameter, that is 0.1V. Hence the On resistance is $0.1V / 5mA = 20 \Omega$.

- Off conductance. This is set using the datasheet information on reverse current. The reverse current is $3\mu A$ for a reverse voltage of 1V. Hence the Off conductance should be set to $3\mu A / 1V = 3e-6$ S.
- **Reverse breakdown voltage Vz**. This parameter should be set to the datasheet working voltage parameter, 4.3V.
- Zener resistance Rz. This needs to be set to a suitable small number. Too small, and the voltage-current relationship becomes very steep, and simulation convergence may not be as efficient. Too large, and the zener voltage will be incorrect. For the Diode block to be representative of the real device, the simulated reverse voltage should be close to 4.3V at 5mA (the reverse bias current provided by the circuit). Allowing a 0.01 V error on the zener voltage at 5mA, R_z will be 0.01V / 5mA = 2 Ω .
- Junction capacitance. This parameter is set to the datasheet diode capacitance value, 450 pF.

🙀 Block Parameters: Diode		×			
-Diode					
This block represents a diode. Use the Diod	e model parameter to select one of the following model types:				
[1] Piecewise Linear Diode. This option invo	es the diode model from the Simscape Foundation Library.				
Piecewise Linear Diode for reverse voltages	[2] Piecewise Linear Zener Diode (i.e. piecewise linear diode with reverse breakdown characteristics). This model is identical to the Piecewise Linear Diode for reverse voltages above the Reverse Breakdown Voltage Vz. For voltages below Vz the diode breaks down with a low corresponding Zener Resistance Rz.				
the thermal voltage, and N is the emission of	xponential diode equation I = Is*(exp(V/(N*vt))-1) where Is is oefficient (>=1). Vt is given by Vt = k*T/e where k is Boltzmar nd e is the magnitude of charge on an electron.				
Parameters					
Main Reverse Breakdown Ohmi	Resistance Junction Capacitance				
Diode model:	Piecewise Linear Zener				
Forward voltage:	0.6	V			
On resistance:	1.6	Ohm 💌			
Off conductance:	3e-6	5			
	OK Cancel	Help Apply			

Block Parameters: Diode		×
	de model parameter to select one of the following model typ	pes:
[1] Piecewise Linear Diode. This option inv	okes the diode model from the Simscape Foundation Library	
	ewise linear diode with reverse breakdown characteristics). es above the Reverse Breakdown Voltage Vz. For voltages b e Rz.	
the thermal voltage, and N is the emission	exponential diode equation I = Is*(exp($\forall/(N^*\forall t))$ -1) where coefficient (>=1). Vt is given by Vt = k*T/e where k is Boltz and e is the magnitude of charge on an electron.	
Parameters		
Main Reverse Breakdown Oh	nic Resistance Junction Capacitance	1
Zener resistance Rz:	2	Ohm 💌
Reverse breakdown voltage Vz:	4.3	V
	OK Cancel	Help Apply

Block Parameters: Diode
Diode
This block represents a diode. Use the Diode model parameter to select one of the following model types:
[1] Piecewise Linear Diode. This option invokes the diode model from the Simscape Foundation Library.
[2] Piecewise Linear Zener Diode (i.e. piecewise linear diode with reverse breakdown characteristics). This model is identical to the Piecewise Linear Diode for reverse voltages above the Reverse Breakdown Voltage Vz. For voltages below Vz the diode breaks down with a low corresponding Zener Resistance Rz.
[3] Exponential Diode. Uses the standard exponential diode equation $I = Is^*(exp(V)(N^*Vt))-1)$ where Is is the Saturation current, Vt is the thermal voltage, and N is the emission coefficient (>=1). Vt is given by $Vt = k^*T/e$ where k is Boltzmann's constant, T is the absolute Temperature of the p-n junction, and e is the magnitude of charge on an electron.
Parameters
Main Reverse Breakdown Ohmic Resistance Junction Capacitance
Junction capacitance: 450 pF
OK Cancel Help Apply

Parameterize an Exponential Diode from a Datasheet

Example 1 uses a piecewise linear approximation to the diode's exponential current-voltage relationship. This results in more efficient simulation, but requires some thought to go into the setting of block parameter values. An alternative is to use a more complex model that is valid for a wider range of voltage and current values. This example uses the Exponential parameterization option of the Diode block.

This model either requires two data points from the diode current-voltage relationship, or values for the underlying equation coefficients, namely the saturation current IS and the emission coefficient N. The BZX384-B4V3 datasheet only provides values for the former case. Some datasheets do not give the necessary data for either case, and you must follow the processes in Example 1 or Example 3 instead.

The two data points in the table below are from the BZX384-B4V3 datasheet current-voltage curve:

Diode forward voltage, $V_{\rm F}$	0.7V	1V
Diode forward current, ${\rm I}_{\rm F}$	5mA	250mA

Set the exponential diode block parameters as follows:

- Currents [I1 I2]. Set to [5 250] mA.
- Voltages [V1 V2]. Set to [0.7 1.0] V.
- **Reverse breakdown voltage BV**. Set to the datasheet working voltage value, 4.3V.
- Ohmic resistance. Leave at its default value of 0.01Ω . This is an example of a parameter that cannot be determined from the datasheet. However, setting its value to zero is not necessarily a good idea, because a small value can help simulation convergence for some circuit topologies. The default value has negligible effect at the working current of 5mA, the additional voltage drop being 5e-3 times 0.01 = 5e-5V. Physically, this term will not be zero because of the connection resistances.

• Zero-bias junction capacitance CJ0. Set to the datasheet diode capacitance value, 450 pF.

A more complex capacitance model is also available for the Diode component with the exponential equation option. However, the datasheet does not provide the necessary data. Moreover, the operation of this circuit is not sufficiently sensitive to voltage-dependent capacitance effects to warrant the extra detail.

Diode This block represents a diode. Use the Diode model parameter to select one of the following model types: [1] Piecewise Linear Diode. This option invokes the diode model from the Simscape Foundation Library. [2] Piecewise Linear Zener Diode (i.e., piecewise linear diode with reverse breakdown characteristics). This model is identical to the Piecewise Linear Diode for reverse voltages above the Reverse Breakdown Voltage V2. For voltages below V2 the diode breaks dowr with a low corresponding Zener Resistance R2. [3] Exponential Diode. Uses the standard exponential diode equation I = Is*(exp(V/(N*Vt))-1) where Is is the Saturation current, Vt the thermal voltage, and N is the emission coefficient (>=1). Vt is given by Vt = (*T/e where k is Boltzmann's constant, T is the absolute Temperature of the p-n junction, and e is the magnitude of charge on an electron. Parameters	Block Parameters: Diode		3
[1] Piecewise Linear Diode. This option invokes the diode model from the Simscape Foundation Library. [2] Piecewise Linear Zener Diode (i.e., piecewise linear diode with reverse breakdown characteristics). This model is identical to the Piecewise Linear Diode for reverse voltages above the Reverse Breakdown Voltage V2. For voltages below V2 the diode breaks down with a low corresponding Zener Resistance R2. [3] Exponential Diode. Uses the standard exponential diode equation I = Is*(exp(V/(N*Vt))-1) where Is is the Saturation current, Vt the thermal voltage, and N is the emission coefficient (>=1). Vt is given by Vt = (*T)e where k is Boltzmann's constant, T is the absolute Temperature of the p-n junction, and e is the magnitude of charge on an electron. Parameters Main Reverse Breakdown Ohnic Resistance Junction Capacitance Diode model: Exponential Parameterization: Use I-V curve data points Currents [11 12]: [5 250] Watages [V1 V2]: [0.7 1.0]	iode		
[2] Piecewise Linear Zener Diode (i.e. piecewise linear diode with reverse breakdown characteristics). This model is identical to the Piecewise Linear Diode for reverse voltages above the Reverse Breakdown Voltage V2. For voltages below V2 the diode breaks dowr with a low corresponding Zener Resistance R2. [3] Exponential Diode. Uses the standard exponential diode equation I = Is*(exp(V/(N*Vt))-1) where Is is the Saturation current, Vt the thermal voltage, and N is the emission coefficient (>=1). Vt is given by Vt = (*T/e where k is Boltzmann's constant, T is the absolute Temperature of the p-n junction, and e is the magnitude of charge on an electron. Parameters	his block represents a diode. Use the Dio	de model parameter to select one of the following model types	:
Piecewise Linear Diode for reverse voltages above the Reverse Breakdown Voltage V2. For voltages below V2 the diode breaks down with a low corresponding Zener Resistance R2. [3] Exponential Diode. Uses the standard exponential diode equation I = Is*(exp(V/(N*Vt))-1) where Is is the Saturation current, Vt the thermal voltage, and N is the emission coefficient (>=1). Vt is given by Vt = k*T/e where k is Boltzmann's constant, T is the absolute Temperature of the p-n junction, and e is the magnitude of charge on an electron. Parameters Main Reverse Breakdown Ohmic Resistance Junction Capacitance Diode model: Exponential	1] Piecewise Linear Diode. This option inv	okes the diode model from the Simscape Foundation Library.	
the thermal voltage, and N is the emission coefficient (>=1). Vt is given by Vt = k*T/e where k is Boltzmann's constant, T is the absolute Temperature of the p-n junction, and e is the magnitude of charge on an electron. Parameters Main Reverse Breakdown Ohnic Resistance Junction Capacitance Diode model: Exponential Parameterization: Use I-V curve data points Currents [I1 12]: [5 250] Woltages [V1 V2]: [0.7 1.0]	iecewise Linear Diode for reverse voltage	es above the Reverse Breakdown Voltage Vz. For voltages belo	
Main Reverse Breakdown Ohmic Resistance Junction Capacitance Diode model: Exponential • Parameterization: Use I-V curve data points • Currents [I1 12]: [5 250] mA • Voltages [V1 V2]: [0.7 1.0] V •	he thermal voltage, and N is the emission	coefficient (>=1). Vt is given by $Vt = k^*T/e$ where k is Boltzma	
Main Reverse Breakdown Ohmic Resistance Junction Capacitance Diode model: Exponential • Parameterization: Use I-V curve data points • Currents [I1 12]: [5 250] mA • Voltages [V1 V2]: [0.7 1.0] V •	arameters		
Diode model: Exponential Parameterization: Use I-V curve data points Currents [I1 12]: [5 250] Voltages [V1 V2]: [0.7 1.0]			
Parameterization: Use I-V curve data points Currents [I1 12]: [5 250] Woltages [V1 V2]: [0.7 1.0]	Main Reverse Breakdown Ohr	mic Resistance Junction Capacitance	1
Currents [I1 I2]: [5 250] mA • Voltages [V1 V2]: [0.7 1.0] V •	Diode model:	Exponential	•
Currents [11 12]: [5 250] mA • Voltages [V1 V2]: [0.7 1.0] V •	Parameterization:	Use I-V curve data points	
Voltages [V1 V2]:	Currents [11 12]:	[5 250]	
Measurement temperature: 25 C V	Voltages [V1 V2]:	[0.7 1.0]	V •
	Measurement temperature:	25	C 💌
OK Cancel Help Appl		OK Cancel	Help Apply

🙀 Block Parameters: Diode	
Diode	
This block represents a diode. Use	the Diode model parameter to select one of the following model types:
[1] Piecewise Linear Diode. This op	tion invokes the diode model from the Simscape Foundation Library.
	.e. piecewise linear diode with reverse breakdown characteristics). This model is identical to the voltages above the Reverse Breakdown Voltage Vz. For voltages below Vz the diode breaks down sistance Rz.
the thermal voltage, and N is the e	andard exponential diode equation I = Is*(exp($V((N^*Vt))-1)$ where Is is the Saturation current, Vt is mission coefficient (>=1). Vt is given by Vt = k*T/e where k is Boltzmann's constant, T is the inction, and e is the magnitude of charge on an electron.
Parameters	
Main Reverse Breakdown	Ohmic Resistance Junction Capacitance
Reverse breakdown voltage BV	4.3 V 💌
	OK Cancel Help Apply

🙀 Block Pa	arameters: Diode					×
Diode						
This block	represents a diode. Use t	he Diode model parame	eter to select one of the	ofollowing model types	:	
[1] Piecew	vise Linear Diode. This opti	on invokes the diode m	odel from the Simscape	Foundation Library.		
Piecewise	vise Linear Zener Diode (i.e Linear Diode for reverse v corresponding Zener Res	oltages above the Rev				
the therm	ential Diode. Uses the sta al voltage, and N is the en femperature of the p-n jur	nission coefficient (>=1). Vt is given by $Vt = k$	*T/e where k is Boltzma		
Parameter	's					
Main	Reverse Breakdown	Ohmic Resistance	Junction Capacitance			
Ohmic r	resistance RS:	0.01			Ohm	•
			OK	Cancel	Help	Apply

Block Parameters: Diode	×
Diode	
This block represents a diode. Use the Diod	de model parameter to select one of the following model types:
[1] Piecewise Linear Diode. This option invo	okes the diode model from the Simscape Foundation Library.
	ewise linear diode with reverse breakdown characteristics). This model is identical to the s above the Reverse Breakdown Voltage Vz. For voltages below Vz the diode breaks down Rz.
the thermal voltage, and N is the emission	exponential diode equation I = Is*(exp(V/(N*Vt))-1) where Is is the Saturation current, Vt is coefficient (>=1). Vt is given by Vt = k*T/e where k is Bokzmann's constant, T is the and e is the magnitude of charge on an electron.
Parameters	
Main Reverse Breakdown Ohm	ic Resistance Junction Capacitance
Junction capacitance:	Fixed or zero junction capacitance
Zero-bias junction capacitance CJO:	450 pF
	OK Cancel Help Apply

Parameterize an Exponential Diode from SPICE Netlist

If a datasheet does not provide all of the data required by the component model, another source is a SPICE netlist for the component. Components are defined by a particular type of SPICE netlist called a subcircuit. The subcircuit defines the coefficients for the defining equations. Most component manufacturers make subcircuits available on their websites. The format is ASCII, and you can directly read off the parameters. The BZX384-B4V3 subcircuit can be obtained from Philips Semiconductors http://www.nxp.com/models/index.html.

The subcircuit data can be used to parameterize the SimElectronics Diode block either in conjunction with the datasheet, or on its own. For example, the Ohmic resistance is defined in the subcircuit as RS = 0.387, thus providing the missing piece of information in Example 2.

An alternative workflow is to use the SimElectronics Additional Components/SPICE-Compatible Components sublibrary. The SPICE Diode block in this sublibrary can be directly parameterized from the subcircuit by setting:

- Saturation current, IS to 1.033e-15
- Ohmic resistance, RS to 0.387
- Emission coefficient, ND to 1.001
- Zero-bias junction capacitance, CJO to 2.715e-10
- Junction potential, VJ to 0.7721
- Grading coefficient, MG to 0.3557
- Capacitance coefficient, FC to 0.5
- Reverse breakdown current, IBV to 0.005
- Reverse breakdown voltage, BV to 4.3

Note that where there is a one-to-one correspondence between subcircuit parameters and datasheet values, the numbers often differ. One reason for this is that datasheet values are sometimes given for maximum values, whereas subcircuit values are normally for nominal values. In this example, the CJO value of 271.5 pF differs from the data sheet capacitance of 450 pF at zero bias for this reason.

🙀 Block Parameters: SPICE Diode						×
SPICE Diode						
This model approximates a SPICE diode. Y The instance parameter OFF and the noise and TOFFSET.						
SCALE is the number of parallel diode insta differs from the AREA parameter, which m						tly. This
You can set the diode temperature to a fix plus TOFFSET.	xed temperature or	to the circuit temp	perature (fro	om the SPICE	Environment Param	eters block)
The block lets you include or exclude capa modeling uses the published equations, wi the voltage across the internal diode junch not adjusted as a function of the breakdo	hich may yield a slig tion, so it is only eff	htly different valu	e than SPIC	E for capacita	nce. The initial cor	ndition VO is
Parameters						
Main Junction Capacitance Re	everse Breakdown	Temperature	1			1
Device area, AREA:	1				m^2	-
Number of parallel devices, SCALE:	1					
Saturation current, IS:	1.033e-15				A/m^2	•
Ohmic resistance, RS:	0.387				m^2*Ohm	-
Emission coefficient, ND:	1.001					
			ж	Cancel	Help	Apply

🙀 Block Parameters: SPICE Diode					×
SPICE Diode					
This model approximates a SPICE diode. Y The instance parameter OFF and the noise and TOFFSET.					
SCALE is the number of parallel diode insta differs from the AREA parameter, which m				vice charge dired	tly. This
You can set the diode temperature to a fix plus TOFFSET.	ed temperature or to the e	circuit temperature (fror	m the SPICE Er	nvironment Parar	meters block)
The block lets you include or exclude capa modeling uses the published equations, wi the voltage across the internal diode junct not adjusted as a function of the breakdo	hich may yield a slightly difl tion, so it is only effective (erent value than SPICE	for capacitan	ce. The initial co	ndition VO is
-Parameters					
Main Junction Capacitance Re	verse Breakdown Terr	nperature			1
Model junction capacitance?:	Yes				-
Zero-bias junction capacitance, CJO:	2.715e-10			F/m^2	•
Junction potential, VJ:	0.7721			۷	•
Grading coefficient, MG:	0.3557				
Capacitance coefficient, FC:	0.5				
Transit time, TT:	0			s	-
Specify initial condition?:	No				•
			1		
		ОК	Cancel	Help	Apply

PICE Diode		
	You specify both model card and instance parameters as instance paramet e model parameters KF and AF are not supported. Additional instance par	
	ances for this device. SCALE multiplies the output current and device char nultiples the device parameters IS, CJO and IBV, and divides RS.	ge directly. Thi
ou can set the diode temperature to a fi lus TOFFSET.	xed temperature or to the circuit temperature (from the SPICE Environment	nt Parameters I
odeling uses the published equations, w ne voltage across the internal diode junc	acitance modeling, initial conditions and reverse breakdown modeling. The hich may yield a slightly different value than SPICE for capacitance. The ir tion, so it is only effective when junction capacitance is present. The brea	nitial condition
ot adjusted as a function of the breakdo	own current IBV.	
arameters		
Main Junction Capacitance R	everse Breakdown Temperature	
Main Sancton Capacitance 14		
Model reverse breakdown?:	Yes	
Model reverse breakdown?:	Yes	
Model reverse breakdown?: Reverse breakdown current, IBV:	Yes 0.005 A/m^2	
Model reverse breakdown?:	Yes	
Model reverse breakdown?: Reverse breakdown current, IBV:	Yes 0.005 A/m^2	:]
Model reverse breakdown?: Reverse breakdown current, IBV:	Yes 0.005 A/m^2	:]
Model reverse breakdown?: Reverse breakdown current, IBV:	Yes 0.005 A/m^2	:]
Model reverse breakdown?: Reverse breakdown current, IBV:	Yes 0.005 A/m^2	:]
Model reverse breakdown?: Reverse breakdown current, IBV:	Yes 0.005 A/m^2	- :]
Model reverse breakdown?: Reverse breakdown current, IBV:	Yes 0.005 A/m^2	:]
Model reverse breakdown?: Reverse breakdown current, IBV:	Yes 0.005 A/m^2	:]

Parameterize an Op-Amp from a Datasheet

The Triangle Wave Generator example model, also described in "Triangle Wave Generator Model" on page 1-32, contains two op-amps, parameterized based on a datasheet for an LM7301. The National Semiconductor datasheet gives the following data for this device:

Gain	97 dB = 7.1 e4
Input resistance	39MΩ
Slew rate	1.25V/µs
Bandwidth	4MHz

The Band-Limited Op-Amp and Finite-Gain Op-Amp blocks have been designed to work from manufacturer datasheets. Implementing detailed op-amp device models, derived from manufacturer SPICE netlist models, is not recommended, because it provides more accuracy than is typically warranted and slows down simulations. The simple parameterization of the SimElectronics op-amp blocks allows you to determine the sensitivity of your circuit to abstracted performance values, such as maximum slew rate and bandwidth. Because of this behavior-based parameterization, you can determine which specification of op-amp is required for a given application. A circuit designer can later match these behavioral parameters, determined from the model, against specific op-amp devices.

Based on the datasheet values above, set the Band-Limited Op-Amp block parameters as follows:

- Gain set to 7.1e4
- Input resistance, Rin set to $39e6\Omega$
- Output resistance, Rout set to zero. The value is not defined, but will be small compared to the 1000Ω load seen by the op-amp.
- **Minimum output, Vmin** set to the negative supply voltage, -20V in this model
- Maximum output, Vmax set to the positive supply voltage, 20V in this model

- Maximum slew rate, Vdot set to 1.25/1e-6 V/s
- Bandwidth, f set to 4e6 Hz

Note that these parameters correspond to the values for +-5 volt operation. The datasheet also gives values for +-2.2V and +-30V operation. It is usually better to pick values for a supply voltage below what your circuit uses, because performance is worse at lower voltages; for example, the gain is less, and the input impedance is less. You can use the variation in op-amp parameters with supply voltage to suggest a typical range of parameter values for which you should check the operation of your circuit.

🙀 Block Parameters: Band-Limite	d Op-Amp	×
Band-Limited Op-Amp		
This block models a band-limited op-amp. If the voltages at the positive and negative pins are denoted Vp and Vm, then the output voltage is given by		
$Vout = A^*(Vp-Vm)^*1/(s/(2^*pi^*f)+1)-Iout^*Rout$		
where A is the gain, Rout is the output resistance, Iout is the output current, s is the Laplace operator, and f is the 3dB bandwidth. The input current is given by (Vp-Vm)/Rin where Rin is the input resistance. The no-load output voltage is limited the range Vmin to Vmax, and the slew rate is limited to +-Vdot.		
The Initial output voltage, V0, sets the initial op-amp output voltage. Note that this does not take account of any voltage drop across Rout. The initial condition is not used if you select the Start simulation from steady state option in the Solver Configuration block.		
Parameters		
Gain, A:	7.1e4	
Input resistance, Rin:	39e6	Ohm 💌
Output resistance, Rout:	0	Ohm 💌
Minimum output, Vmin:	-20	V
Maximum output, Vmax:	20	V
Maximum slew rate, Vdot:	1.25/1e-6	V/s 💌
Bandwidth, f:	4e6	Hz
Initial output voltage, VO:	0	V
	OK Cancel	Help Apply

Additional Parameterization Workflows

There are several other ways to parameterize and validate your model:

In this section ...

"Validation Using Data from SPICE Tool" on page 2-17

"Parameter Tuning Against External Data" on page 2-17

"Building an Equivalent Model of a SPICE Netlist" on page 2-17

Validation Using Data from SPICE Tool

One way to validate a parameterized SimElectronics component is to compare its behavior to data from specialist circuit simulation tool that uses a manufacturer SPICE netlist of the device. If doing this, it is important to create a test harness for the component that exercises it over the relevant operating points and frequencies

Parameter Tuning Against External Data

If you have lab measurements of the device, or data from another simulation environment, you can use this to tune the parameters of the equivalent SimElectronics component. For an example of parameter tuning, see the example Solar Cell Parameter Extraction From Data.

Building an Equivalent Model of a SPICE Netlist

In Example 3, parameterization from a SPICE netlist is relatively straightforward because the netlist defines a single device (the diode) plus corresponding model card (the parameters). Conversely, a netlist for an op-amp may have more than ten devices, plus supporting model cards. In principle it is possible to build your own equivalent model of a more complex device by making use of the SPICE-Compatible Components sublibrary, and connecting them together using the information in the netlist. Before embarking on this you should ensure that the SPICE-Compatible Components sublibrary has all of the component models that you need.

If the device models you wish to model are complex (hundreds of components), then cosimulation with an external circuit simulator may be a better approach.

Selecting the Output Model for Logic Blocks

In this section ...

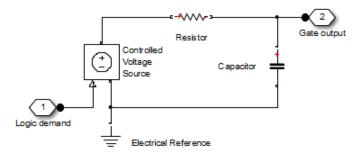
"Available Output Models" on page 2-18

"Quadratic Model Output and Parameters" on page 2-19

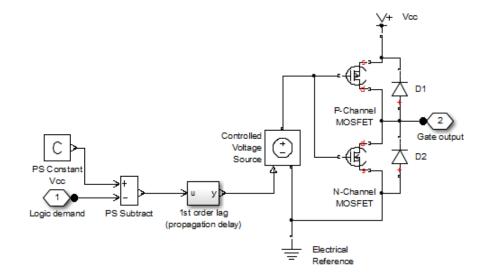
Available Output Models

The blocks in the Logic sublibrary of the Integrated Circuits library provide a choice of two output models:

• Linear — Models the gate output as a voltage source driving a series resistor and capacitor connected to ground. This is suitable for logic circuit operation under normal conditions and when the logic gate drives other high-impedance CMOS gates. The block sets the value of the gate output capacitor such that the resistor-capacitor time constant equals the **Propagation delay** parameter value. The linear output model is shown in the following illustration.



• Quadratic — Models the gate output in terms of a complementary N-channel and P-channel MOSFET pair. This adds more fidelity, which becomes relevant if drawing higher currents from the gate output, or if exercising the gate under fault conditions. In addition, the gate input demand is lagged to approximate the **Propagation delay** parameter value. Default parameters are representative of the 74HC logic gate family. The quadratic output model is shown in the next illustration.



Use the **Output current-voltage relationship** parameter on the **Outputs** tab of the block dialog box to specify the output model.

For most system models, MathWorks recommends selecting the linear option because it supports faster simulation. If necessary, you can use the more detailed output model to validate simulation results obtained from the simpler model.

Quadratic Model Output and Parameters

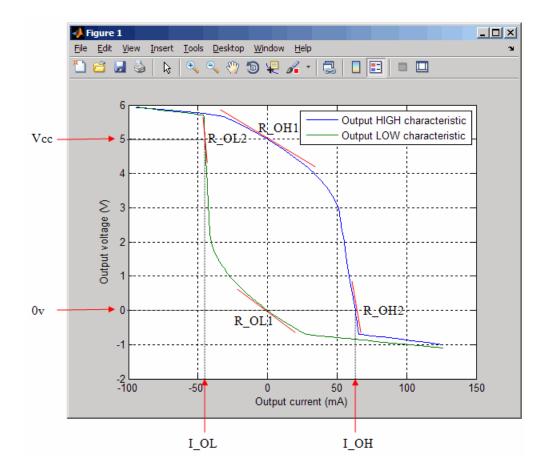
If you select the quadratic model, use the following parameters to control the block output:

- **Supply voltage** Supply voltage value (Vcc) applied to the gate in your circuit. The default value is 5 V.
- **Measurement voltage** The gate supply voltage for which mask data output resistances and currents are defined. The default value is 5 V.
- Logic HIGH output resistance at zero current and at I_OH A row vector [*R_OH1 R_OH2*] of two resistance values. The first value *R_OH1* is the gradient of the output voltage-current relationship when the gate is

logic HIGH and there is no output current. The second value R_OH2 is the gradient of the output voltage-current relationship when the gate is logic HIGH and the output current is I_OH . The default value is [25 250] Ω .

- Logic HIGH output current I_OH when shorted to ground The resulting current when the gate is in the logic HIGH state, but the load forces the output voltage to zero. The default value is 63 mA.
- Logic LOW output resistance at zero current and at I_OL A row vector [$R_OL1 R_OL2$] of two resistance values. The first value R_OL1 is the gradient of the output voltage-current relationship when the gate is logic LOW and there is no output current. The second value R_OL2 is the gradient of the output voltage-current relationship when the gate is logic LOW and the output current is I_OL . The default value is [30 800] Ω .
- Logic LOW output current I_OL when shorted to Vcc The resulting current when the gate is in the logic LOW state, but the load forces the output voltage to the supply voltage Vcc. The default value is -45 mA.
- **Propagation delay** Time it takes for the output to swing from LOW to HIGH or HIGH to LOW after the input logic levels change. For quadratic output, it is implemented by the lagged gate input demand. The default value is 25 ns.
- **Protection diode on resistance** The gradient of the voltage-current relationship for the protection diodes when forward biased. The default value is 5 Ω .
- **Protection diode forward voltage** The voltage above which the protection diode is turned on. The default value is 0.6 V.

The following graphic illustrates the quadratic output model parameterization, using the default parameter output characteristics for a +5V supply.



Simulating Thermal Effects in Semiconductors

In this section ...

"Using the Thermal Ports" on page 2-22

"Thermal Model for Semiconductor Blocks" on page 2-24

"Thermal Mass Parameterization" on page 2-25

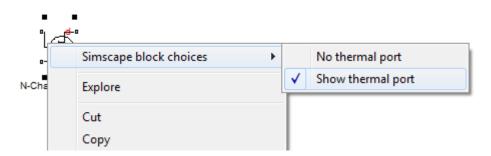
"Electrical Behavior Depending on Temperature" on page 2-26

"Improving Numerical Performance" on page 2-26

Using the Thermal Ports

Certain SimElectronics blocks, for example, the blocks in the Semiconductors library, contain an optional thermal port. This port is hidden by default. If you want to simulate the generated heat and device temperature, expose the thermal port on a particular block instance in your block diagram:

- 1 Right-click the block where you want to show the thermal port.
- 2 From the context menu, select Simscape block choices > Show thermal port.



When the thermal port is exposed, the block dialog box contains an additional tab, **Thermal Port**. For semiconductor devices, the tab always contains the same set of parameters.

Parameters				
Main Ohmic Resistance Jun	ction Capacitance Temperature Dependence	Thermal Port		
Junction-case and case-ambient (or case-heatsink) thermal resistances, [R_JC R_CA]:	[010]	K/W 👻		
Thermal mass parameterization:	By thermal time constants	▼]		
Junction and case thermal time constants, [t_J t_C]:	[010]	S •		
Junction and case initial temperatures, [T_J T_C]:	[25 25]	С –		

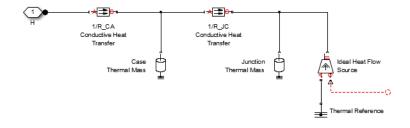
- Junction case and case-ambient (or case-heatsink) thermal resistances, $[R_JC R_CA]$ A row vector $[R_JC R_CA]$ of two thermal resistance values, represented by the two Conductive Heat Transfer blocks in the "Thermal Model for Semiconductor Blocks" on page 2-24. The first value R_JC is the thermal resistance between the junction and case. The second value R_CA is the thermal resistance between port H and the device case. See "Thermal Model for Semiconductor Blocks" on page 2-24 for further details. The default value is $[0 \ 10 \]K/W$.
- Thermal mass parameterization Select whether you want to parameterize the thermal masses in terms of thermal time constants (By thermal time constants), or specify the thermal mass values directly (By thermal mass). For more information, see "Thermal Mass Parameterization" on page 2-25. The default is By thermal time constants.
- Junction and case thermal time constants, $[t_J t_C] A$ row vector $[t_J t_C]$ of two thermal time constant values. The first value t_J is the junction time constant. The second value t_C is the case time constant. This parameter is only visible when you select By thermal time constants for the **Thermal mass parameterization** parameter. The default value is $[0 \ 10 \]$ s.
- Junction and case thermal masses, $[M_J M_C]$ A row vector $[M_J M_C]$ of two thermal mass values. The first value M_J is the junction thermal mass. The second value M_C is the case thermal mass. This parameter is only visible when you select By thermal mass for the **Thermal mass parameterization** parameter. The default value is $[0 \ 1] J/K$.

• Junction and case initial temperatures, $[T_J T_C]$ — A row vector [$T_J T_C$] of two temperature values. The first value T_J is the junction initial temperature. The second value T_C is the case initial temperature. The default value is [25 25] C.

For more information on selecting the parameter values, see "Thermal Model for Semiconductor Blocks" on page 2-24 and "Improving Numerical Performance" on page 2-26. For explanation of the relationship between the **Thermal Port** and **Temperature Dependence** tabs in a block dialog box, see "Electrical Behavior Depending on Temperature" on page 2-26.

Thermal Model for Semiconductor Blocks

All blocks with optional thermal ports include an internal thermal model with thermal masses and resistances. The purpose of including this model internally is to keep your diagram uncluttered by the thermal model. The following figure shows an equivalent model of the internal thermal model for semiconductor devices.



The port H in the diagram corresponds to the thermal port H of the block. The two Thermal Mass blocks represent the thermal mass of the device case and the thermal mass of the semiconductor junction, respectively. The Ideal Heat Flow Source block inputs heat to the model with value equal to the electrically generated heat from the device.

The two Conductive Heat Transfer blocks model the thermal resistances. Resistance R_JC (conductance 1/R_JC) represents the thermal resistance between junction and case. Because of this resistance, under normal conditions the junction will be hotter than the case. Resistance R_CA represents the thermal resistance between port H and the device case. If the device has no heatsink, then in your model you should connect port H to an Ideal Temperature Source with its temperature set to ambient conditions. If your device does have an external heatsink, then you must model the heatsink externally to the device, and connect the heatsink thermal mass directly to port H.

If you wish to keep all or part of the thermal model of the device external to the model, you can set the necessary block parameters to zero. The following rules apply:

- Case thermal mass must be greater than zero.
- Junction thermal mass can only be set to zero if the junction-case resistance is also set to zero.
- If both case and junction thermal masses are defined, but junction-case resistance is zero, then the initial temperatures assigned to junction and case must be identical.

Thermal Mass Parameterization

Datasheets usually quote both of the thermal resistances, but rarely give values for thermal masses. There are two parameterization options for the thermal masses:

- By thermal time constants Parameterize the thermal masses in terms of thermal time constants. This is the default.
- By thermal mass Specify the thermal mass values directly.

The thermal time constants t_J and t_C are defined as follows:

 $t_J = M_J \cdot R_J C$

 $t_C = M_C \cdot R_CA$

where M_J and M_C are the junction and case thermal masses, respectively, R_JC is the thermal resistance between junction and case, and R_CA is the thermal resistance between port H and the device case.

You can determine the case time constant by experimental measurement. If data is not available for the junction time constant, you can either omit it and set the junction-case resistance to zero, or you can set the junction time constant to a typical value of one tenth of the case time constant. The alternative is to estimate thermal masses based on device dimensions and averaged material specific heats.

Electrical Behavior Depending on Temperature

For blocks with optional thermal ports, there are two simulation options:

- Simulate the generated heat, device temperature, and the effect of temperature on the electrical equations.
- Simulate the generated heat and device temperature, but do not include effect of temperature on the electrical equations. Use this option when the impact of temperature on the electrical equations is small over the temperature range to be simulated, or where the primary task of the simulation is to capture the heat generated to support system-level design.

The thermal port and the **Thermal Port** tab of the block dialog box let you simulate the generated heat and device temperature. The **Thermal Dependence** tab of the block dialog box lets you model the effect of temperature of the semiconductor junction on the electrical equations. Therefore:

- To simulate all the temperature effects, show the block's thermal port and set the **Parameterization** parameter on the **Thermal Dependence** tab to Model temperature dependence (or, for blocks with a choice of options for modeling temperature dependence, select one of these options, for example, Use an I-V data point at second measurement temperature).
- To simulate just the generated heat and device temperature, show the block's thermal port but set the **Parameterization** parameter on the **Thermal Dependence** tab to None Simulate at parameter measurement temperature.

Improving Numerical Performance

It is very important that you set realistic values for thermal masses and resistances. Otherwise, junction temperatures can become extreme, and out of range for valid results, which in turn may manifest itself as numerical difficulties when simulating. A simple test to see if numerical difficulties are a result of unrealistic thermal values is to turn off the temperature dependence for the electrical equations, by setting the **Parameterization** parameter on the **Thermal Dependence** tab to None Simulate at parameter measurement temperature.

The thermal time constants are generally much slower than electrical time constants, so the thermal aspects of your model are unlikely to dictate the maximum fixed time step you can simulate at (for example, for hardware-in-the-loop simulations). However, if you need to remove detail (for example, to speed up simulation), the junction thermal mass time constant is typically an order of magnitude faster than the case thermal mass time constant. You can remove the effect of the junction thermal mass by setting the junction thermal mass to zero and also setting the junction-case thermal resistance to zero.

Simulating Thermal Effects in Rotational and Translational Actuators

In this section...

"Using the Thermal Ports" on page 2-28

"Thermal Model for Actuator Blocks" on page 2-30

Using the Thermal Ports

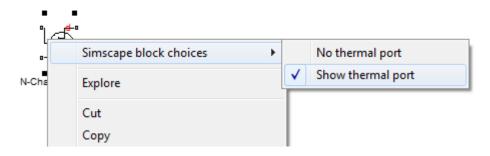
All blocks that represent rotational and translational actuators with electrical windings can optionally show a thermal port for each electrical winding. So, for example:

- A DC Motor block can optionally show a single thermal port corresponding to the armature
- A Shunt Motor block can optionally show two thermal ports, one for the stator winding and one for the field winding

The thermal port represents copper resistance losses which convert electrical power to heat. These losses are sometimes referred to as i^2R losses. The thermal ports do not represent iron losses due to, for example, Eddy currents and hysteresis.

The thermal ports are hidden by default. To expose the thermal port on a particular block instance in your block diagram:

- 1 Right-click the block where you want to show the thermal port.
- 2 From the context menu, select Simscape block choices > Show thermal port.



When the thermal port is exposed, the block dialog box contains two additional tabs, **Temperature Dependence** and **Thermal Port**. For actuator blocks with single winding, these tabs always contain the same set of parameters.

ure	0.00393		1/K
rature:	25		C ·
		0.00393	0.00393

- **Resistance temperature coefficient** Parameter α in the equation defining resistance as a function of temperature, as described in "Thermal Model for Actuator Blocks" on page 2-30. The default value is for copper, and is 0.00393 1/K.
- **Measurement temperature** The temperature for which motor parameters are defined. The default value is 25 C.

Parameters				
Electrical Torque Mechanic	al Temperature Dependence Thermal Port			
Thermal mass:	100]/К		
Initial temperature:	25	C -		
·				

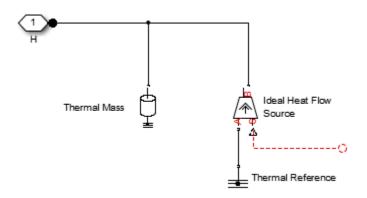
- **Thermal mass** Thermal mass of the electrical winding, defined as the energy required to raise the temperature by one degree. The default value is 100 J/K.
- Initial temperature The temperature of the thermal port at the start of simulation. The default value is 25 C.

For more information on selecting the parameter values, see "Thermal Model for Actuator Blocks" on page 2-30.

Parameters for actuator blocks with two windings differ, and are described on the respective block reference pages.

Thermal Model for Actuator Blocks

The following illustration shows the thermal port model used by the actuator blocks. The heat generated by the copper windings is provided as an input to the S physical signal input port of the Ideal Heat Flow Source. The thermal mass represents the lumped thermal mass of the copper winding where thermal mass is defined as the energy required to raise its temperature by one degree. If the mass is denoted M and the specific heat capacity is $c_{\rm p}$, then thermal mass is $M c_{\rm p}$.



Winding resistance is assumed linearly dependent on temperature, and is given by:

$$R = R_0 (1 + \alpha (T - T_0))$$

where:

- R is the resistance at temperature T.
- R_0 is the resistance at the measurement (or reference) temperature T_0 .
- α is the resistance temperature coefficient. A typical value for copper is 0.00393/K.





Examples

Use this list to find examples in the documentation.

Examples

"DC Motor Model" on page 1-18 "Triangle Wave Generator Model" on page 1-32

Index

A

accuracy model parameter values 1-16 model parameters that affect 1-15

B

blocks logic blocks output 2-18

С

connecting blocks Simulink to SimElectronics[®] Physical blocks 1-11

L

libraries SimElectronics[®] 1-6

M

models SimElectronics® blocks 1-6

0

opening

block libraries 1-6

S

SimElectronics® required and related products 1-5 SimElectronics® libraries 1-6 how to open 1-6 speed model parameter values 1-16 model parameters that affect 1-15

T

troubleshooting electrical models 1-16 troubleshooting simulation issues 1-16

W

workflow SimElectronics[®] 1-10 workflow example SimElectronics[®] electrical 1-32 SimElectronics[®] electromechanical 1-18